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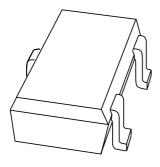
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

# **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# **BF824W**PNP medium frequency transistor

Product data sheet Supersedes data of 1997 Jul 07 1999 Apr 15



NXP Semiconductors Product data sheet

# PNP medium frequency transistor

**BF824W** 

#### **FEATURES**

- Low current (max. 25 mA)
- Low voltage (max. 30 V).

#### **APPLICATIONS**

• RF stages in FM front-ends in common base configuration.

#### **DESCRIPTION**

PNP medium frequency transistor in a SOT323 plastic package.

#### **MARKING**

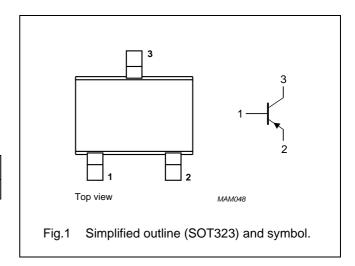
TYPE NUMBER	MARKING CODE(1)		
BF824W	F8*		

#### Note

\* = - : Made in Hong Kong.
 \* = t : Made in Malaysia.

#### **PINNING**

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-30	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-30	٧
$V_{EBO}$	emitter-base voltage	open collector	_	-4	٧
I <sub>C</sub>	collector current (DC)		_	-25	mA
I <sub>CM</sub>	peak collector current		-	-25	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	-	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

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# PNP medium frequency transistor

**BF824W** 

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	625	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	$I_E = 0; V_{CB} = -30 \text{ V}$	_	-50	nA
		$I_E = 0$ ; $V_{CB} = -30 \text{ V}$ ; $T_j = 150 ^{\circ}\text{C}$	-	-10	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = -4 V	_	-100	nA
h <sub>FE</sub>	DC current gain	$I_C = -1 \text{ mA}; V_{CE} = -10 \text{ V}$	25	_	
		$I_C = -4 \text{ mA}; V_{CE} = -10 \text{ V}$	25	_	
$V_{BE}$	base-emitter voltage	$I_C = -4 \text{ mA}; V_{CE} = -10 \text{ V}$	_	-900	mV
$C_{rb}$	feedback capacitance	$I_C = 0$ ; $V_{CE} = -10 \text{ V}$ ; $f = 1 \text{ MHz}$	_	0.3	pF
f <sub>T</sub>	transition frequency	$V_{CE} = -10 \text{ V; } f = 100 \text{ MHz; note 1}$			
		$I_C = -1 \text{ mA}$	250	_	MHz
		$I_C = -4 \text{ mA}$	400	_	MHz
		$I_C = -8 \text{ mA}$	390	_	MHz

#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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NXP Semiconductors Product data sheet

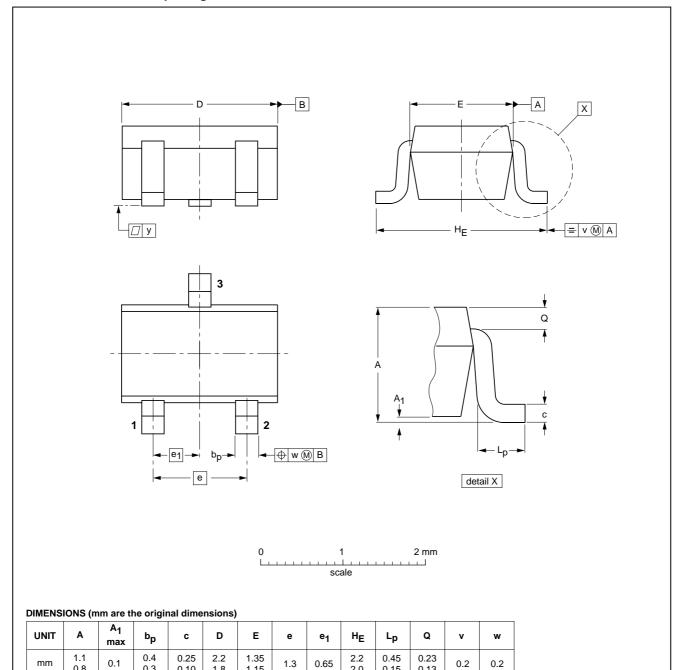
# PNP medium frequency transistor

**BF824W** 

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

**SOT323** 



OUTLINE	REFERENCES		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE
SOT323			SC-70			97-02-28

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### PNP medium frequency transistor

**BF824W** 

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

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## **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

#### **Contact information**

For additional information please visit: http://www.nxp.com

For sales offices addresses send e-mail to: salesaddresses@nxp.com

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